

### General Description

It is mainly suitable for low voltage applications such as automotive, DC/DC converters and a load switch in battery powered applications

### FEATURES

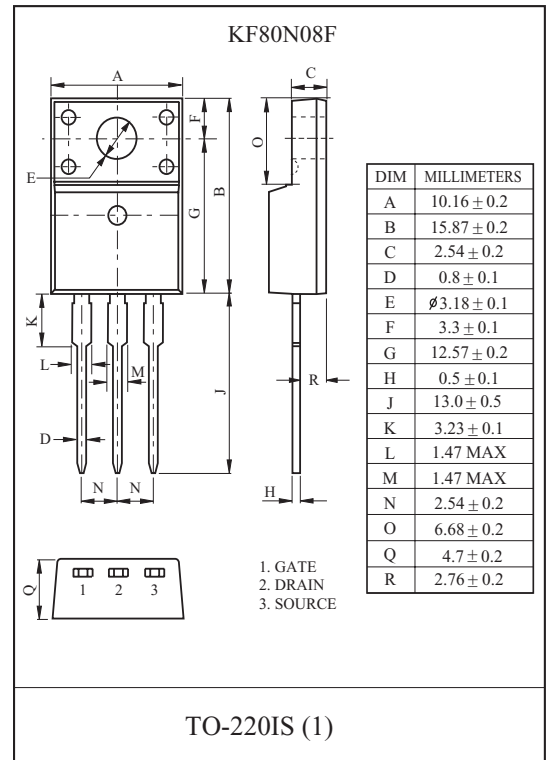
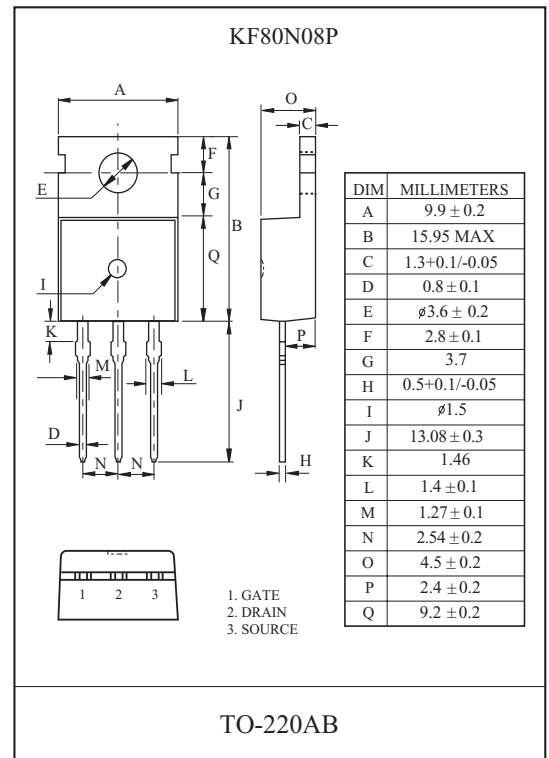
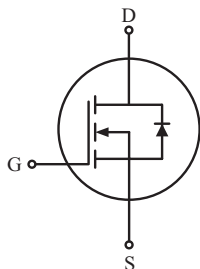
- $V_{DSS} = 75V$ ,  $I_D = 80A$
- Drain-Source ON Resistance :  
 $R_{DS(ON)} = 10m\ \Omega$  (Max.) @  $V_{GS} = 10V$

### MAXIMUM RATING (Tc=25 °C)

CHARACTERISTIC	SYMBOL	RATING		UNIT
		KF80N08P	KF80N08F	
Drain-Source Voltage	$V_{DSS}$	75		V
Gate-Source Voltage	$V_{GSS}$	±20		V
Drain Current	@T <sub>c</sub> =25 °C	80	56	A
	@T <sub>c</sub> =100 °C	76	39	
	Pulsed (Note1)	$I_{DP}$	320	
Single Pulsed Avalanche Energy (Note 2)	$E_{AS}$	1200		mJ
Repetitive Avalanche Energy (Note 1)	$E_{AR}$	18		mJ
Peak Diode Recovery dv/dt (Note 3)	dv/dt	4.5		V/ns
Drain Power Dissipation	T <sub>c</sub> =25 °C	230	62.5	W
	Derate above 25 °C	1.54	0.42	
Maximum Junction Temperature	T <sub>j</sub>	175		°C
Storage Temperature Range	T <sub>stg</sub>	-55 ~ 175		°C
<b>Thermal Characteristics</b>				
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	0.65	2.4	°C/W
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	62.5	62.5	°C/W

\* : Drain current limited by maximum junction temperature.

### PIN CONNECTION



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## ELECTRICAL CHARACTERISTICS (Tc=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D=250\mu A, V_{GS}=0V$	75	-	-	V
Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_j$	$I_D=250\mu A$ , Referenced to 25 °C	-	0.11	-	V/°C
Drain Cut-off Current	$I_{DSS}$	$V_{DS}=75V, V_{GS}=0V$ ,	-	-	10	$\mu A$
Gate Threshold Voltage	$V_{th}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	-	4	V
Gate Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
Drain-Source ON Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=40A$	-	8.5	10.0	m $\Omega$
<b>Dynamic</b>						
Total Gate Charge	$Q_g$	$V_{DS}=60V, I_D=80A$ $V_{GS}=10V$ (Note4,5)	-	107	-	nC
Gate-Source Charge	$Q_{gs}$		-	20	-	
Gate-Drain Charge	$Q_{gd}$		-	47	-	
Turn-on Delay time	$t_{d(on)}$	$V_{DD}=37.5V$ $I_D=80A$ $R_G=25\Omega$ (Note4,5)	-	63	-	ns
Turn-on Rise time	$t_r$		-	228	-	
Turn-off Delay time	$t_{d(off)}$		-	217	-	
Turn-off Fall time	$t_f$		-	150	-	
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V, f=1.0MHz$	-	3860	-	pF
Output Capacitance	$C_{oss}$		-	840	-	
Reverse Transfer Capacitance	$C_{rss}$		-	175	-	
<b>Source-Drain Diode Ratings</b>						
Continuous Source Current	$I_S$	$V_{GS}<V_{th}$	-	-	80	A
Pulsed Source Current	$I_{SP}$		-	-	320	
Diode Forward Voltage	$V_{SD}$	$I_S=80A, V_{GS}=0V$	-	-	1.5	V
Reverse Recovery Time	$t_{rr}$	$I_S=80A, V_{GS}=0V$ , $dI_S/dt=100A/\mu s$	-	114	-	ns
Reverse Recovery Charge	$Q_{rr}$		-	610	-	$\mu C$

Note 1) Repetivity rating : Pulse width limited by junction temperature.

Note 2)  $L=138\mu H, I_S=80A, V_{DD}=50V, R_G=25\Omega$ , Starting  $T_j=25\text{ }^\circ\text{C}$ .

Note 3)  $I_S \leq 7.0A, dI/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$ , Starting  $T_j=25\text{ }^\circ\text{C}$ .

Note 4) Pulse Test : Pulse width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .

Note 5) Essentially independent of operating temperature.

## Marking

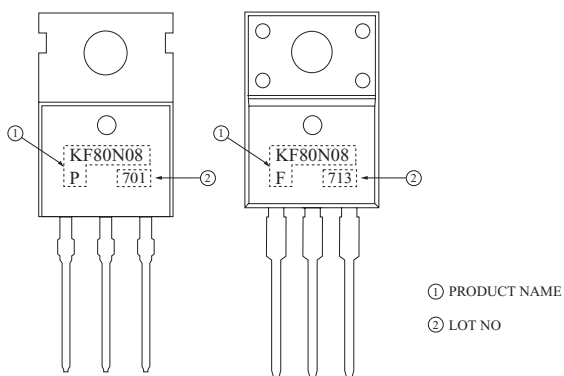


Fig1.  $I_D - V_{DS}$

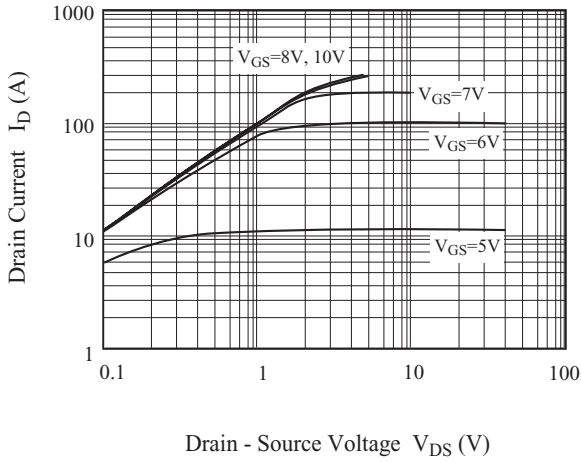


Fig2.  $I_D - V_{GS}$

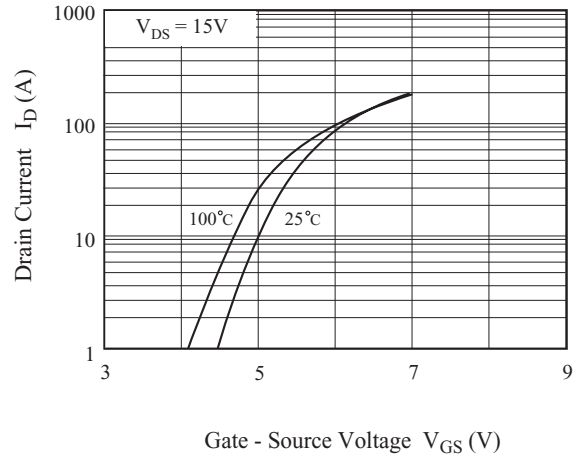


Fig3.  $BV_{DSS} - T_j$

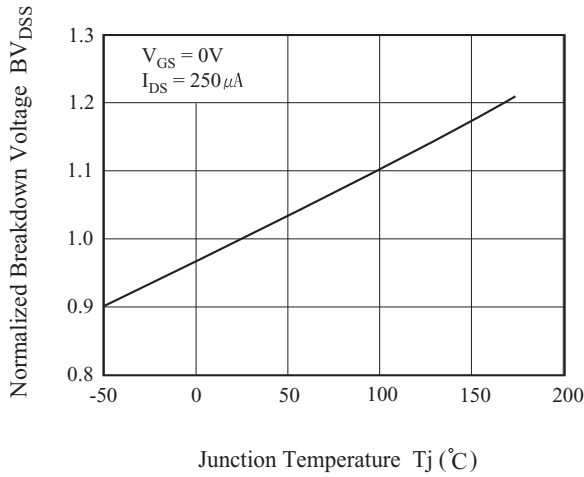


Fig4.  $R_{DS(ON)} - I_D$

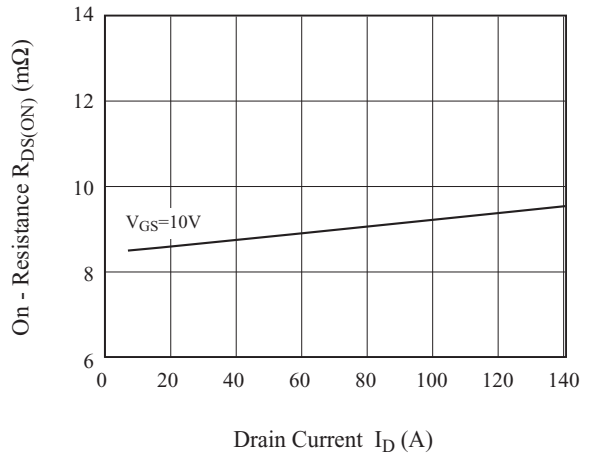


Fig5.  $I_S - V_{SD}$

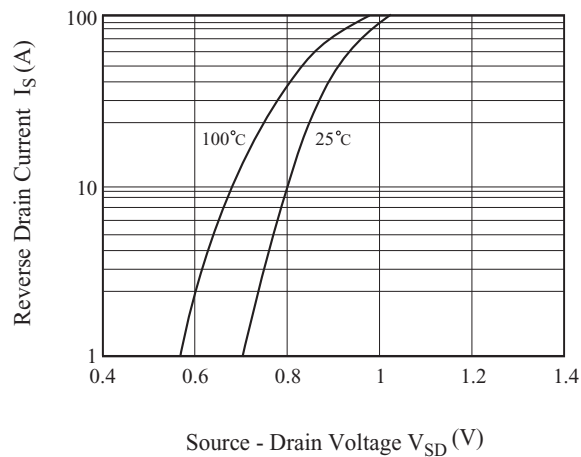
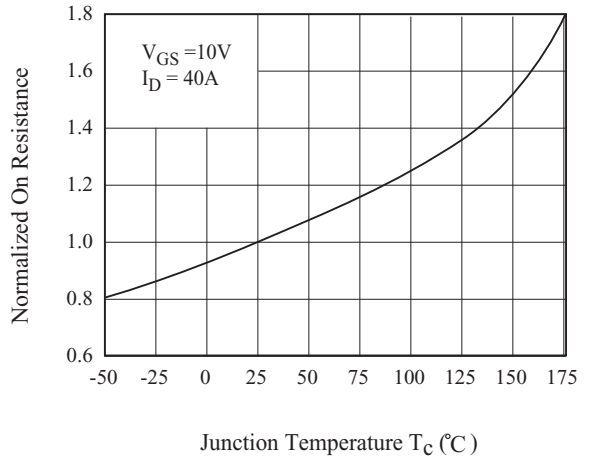


Fig6.  $R_{DS(ON)} - T_C$



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Fig 7. C - V<sub>DS</sub>

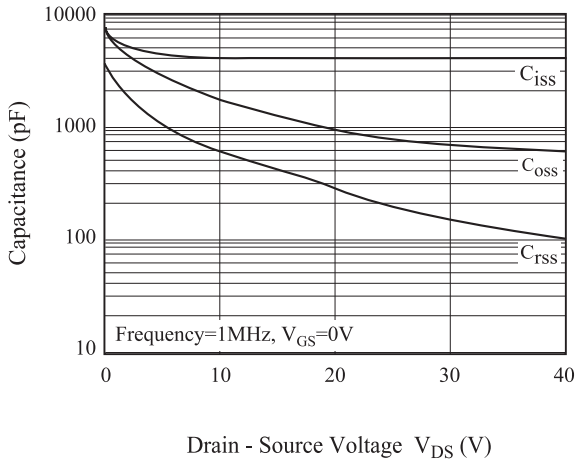


Fig8. Q<sub>g</sub>- V<sub>GS</sub>

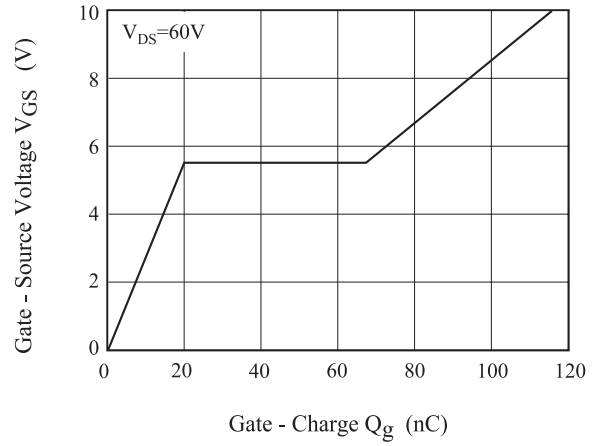


Fig9. Safe Operation Area

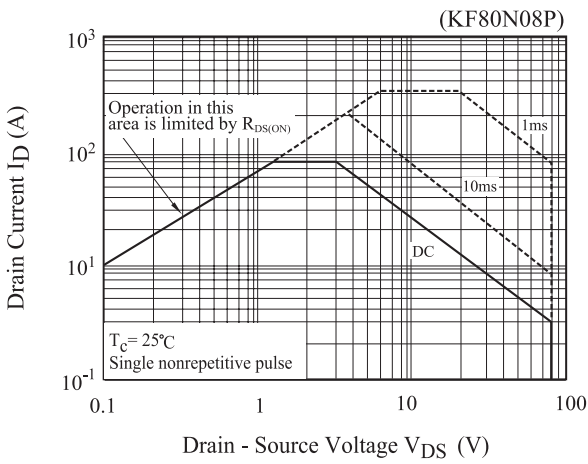


Fig10. Safe Operation Area

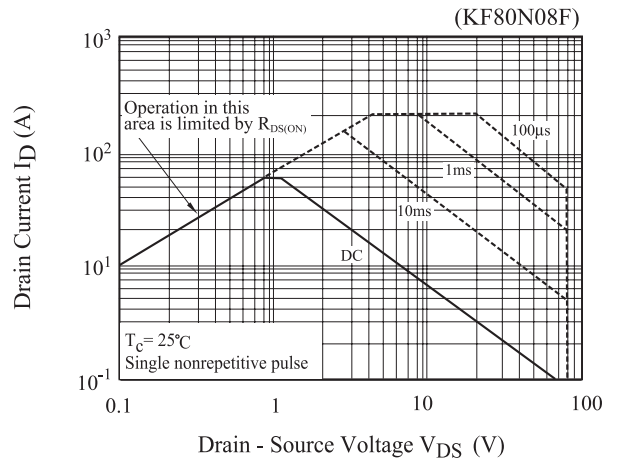
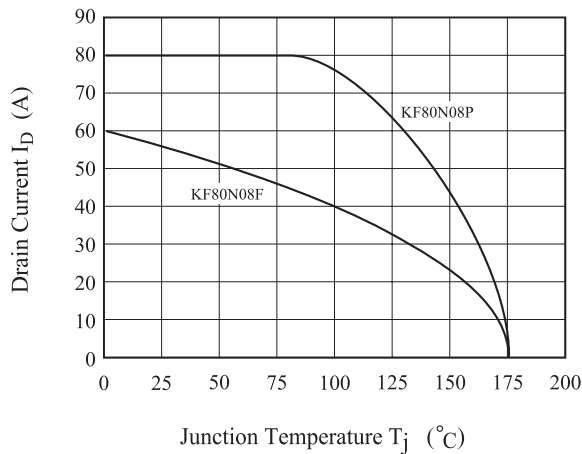


Fig11. I<sub>D</sub> - T<sub>j</sub>



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Fig12. Transient Thermal Response Curve

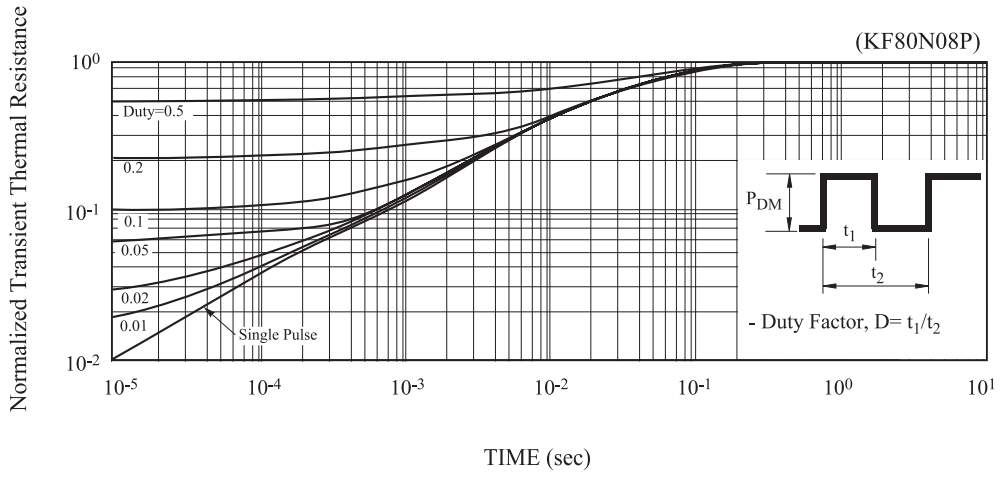


Fig13. Transient Thermal Response Curve

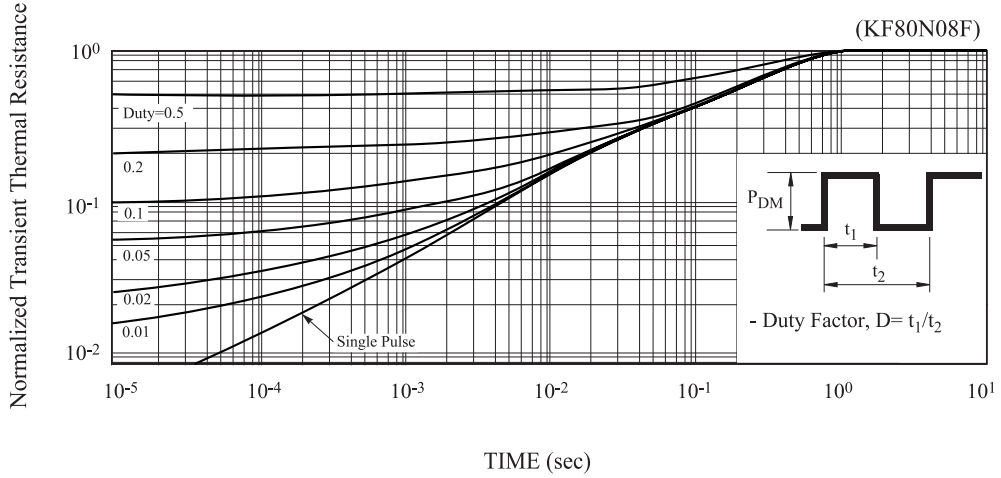


Fig14. Gate Charge

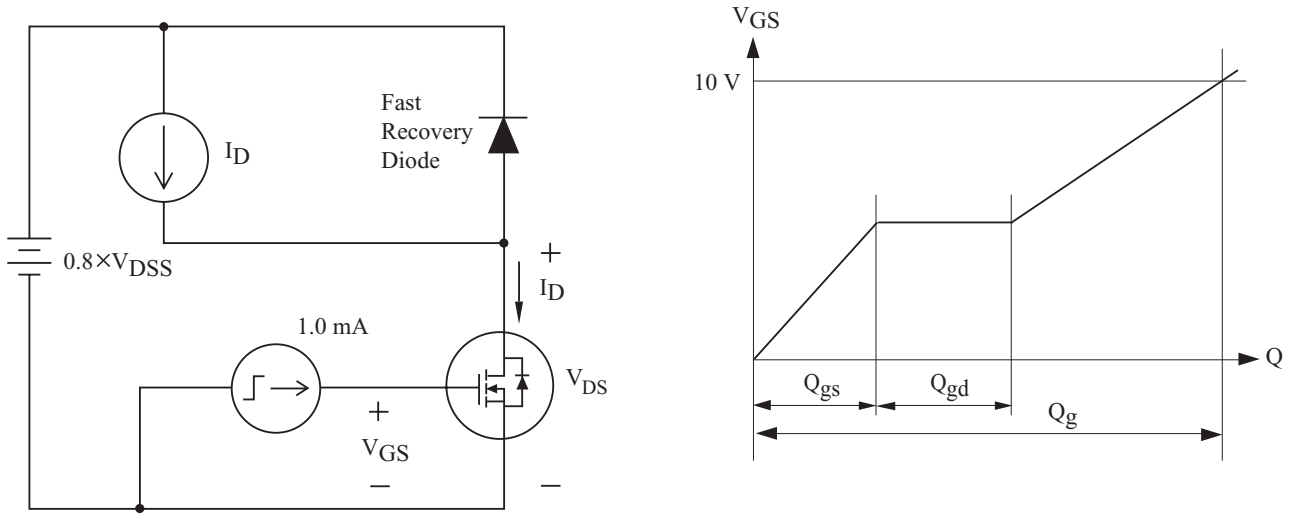


Fig15. Single Pulsed Avalanche Energy

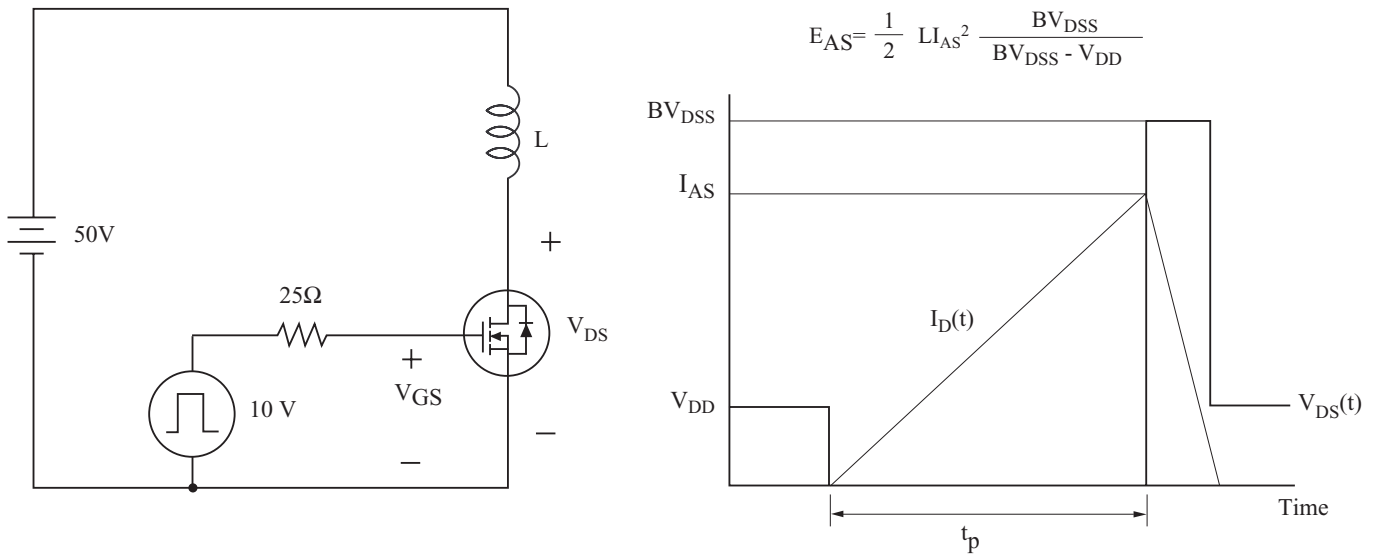


Fig16. Resistive Load Switching

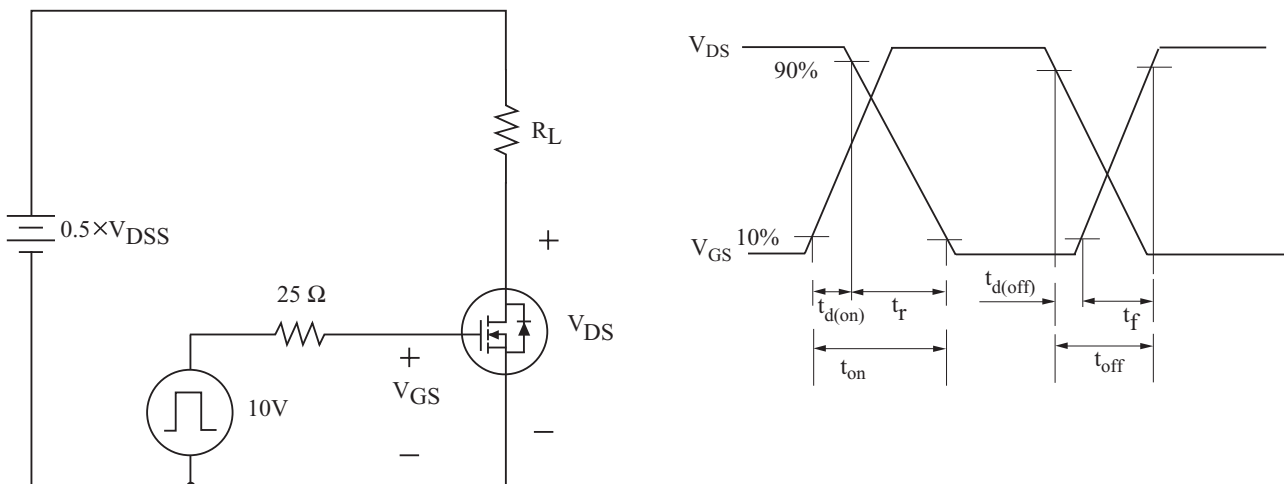


Fig17. Source - Drain Diode Reverse Recovery and  $dv/dt$

